

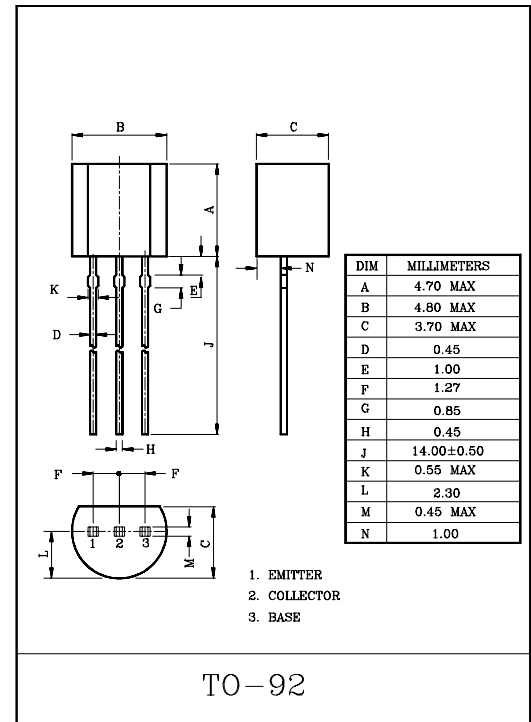
VOLTAGE REGULATOR, RELAY,
RAMP DRIVER, INDUSTRIAL USE

FEATURES

- High Voltage : $V_{CEO}=60V(\text{Min.})$.
- High Current : $I_C(\text{Max.})=1A$.
- High Transition Frequency : $f_T=150\text{MHz}(\text{Typ.})$.
- Wide Area of Safe Operation.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	80	V
Collector-Emitter Voltage		V_{CEO}	60	V
Emitter-Base Voltage		V_{EBO}	5	V
Collector Current	DC	I_C	1	A
	Pulse	I_{CP}	2	
Collector Power Dissipation		P_C	625	mW
Junction Temperature		T_j	150	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	$-55\sim 150$	$^\circ\text{C}$



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V, I_E=0$	—	—	100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=4V, I_C=0$	—	—	100	nA
DC Current Gain	$h_{FE}(1)$	$V_{CE}=2V, I_C=50\text{mA}$	100	—	320	
	$h_{FE}(2)$	$V_{CE}=2V, I_C=1A$	30	—	—	
Collector-Emitter Breakdown Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$	60	—	—	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$	—	0.15	0.5	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$	—	0.85	1.2	V
Transition Frequency	f_T	$V_{CE}=10V, I_C=50\text{mA}$	—	150	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, f=1\text{MHz}$	—	12	—	pF

Note : $h_{FE}(1)$ Classification Y:100~200, GR:160~320

